

Report from the Photodetectors Group:

October 7, 2015

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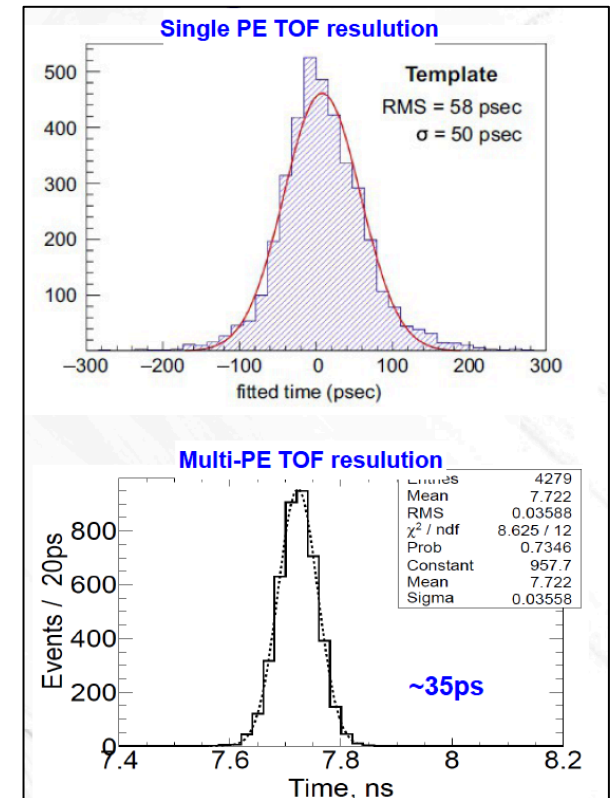
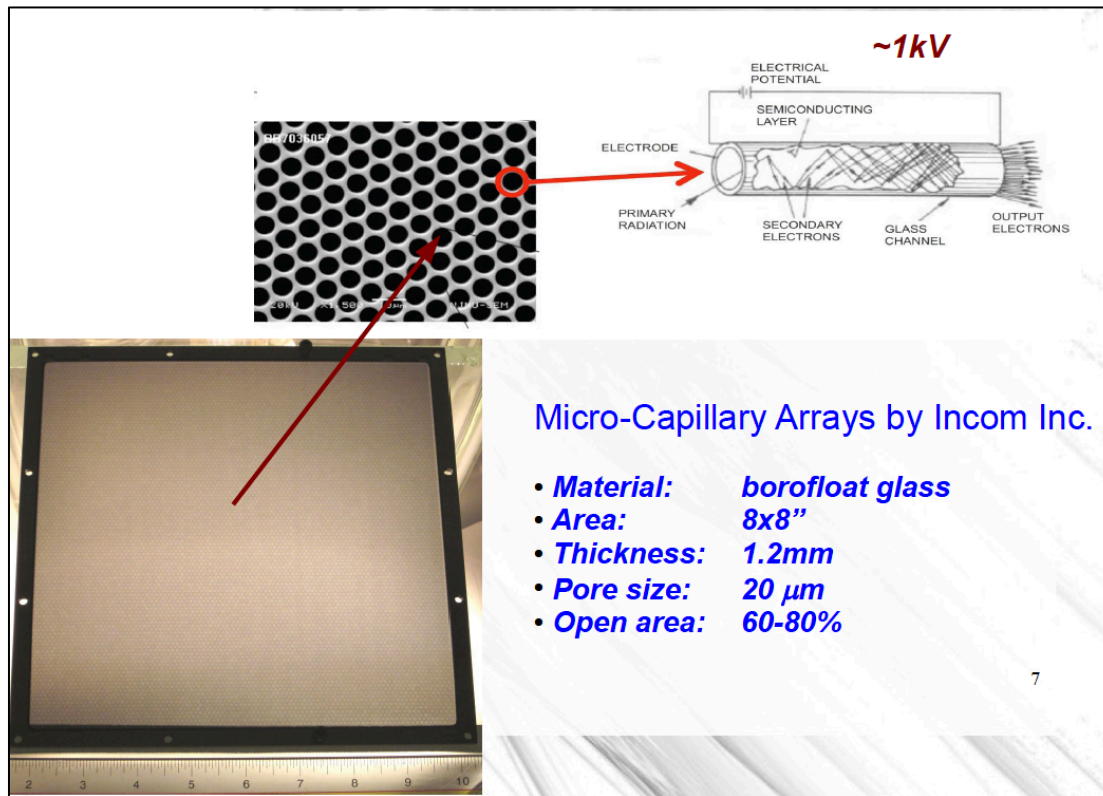


Brief Introduction

- **Science Drivers**
 - **Neutrinoless Double Beta Decay**
 - **Higgs**
 - **CLFV**
 - **Dark Matter Direct Detection**
 - **Neutrino CP violation and Mass Ordering**
 - **Neutrino Astrophysics**
 - **Proton Decay**
- **Speed**
- **Spectral Sensitivity**
- **Cost**
- **Size**
- **Radiopurity**
- **Energy to Light Conversion**

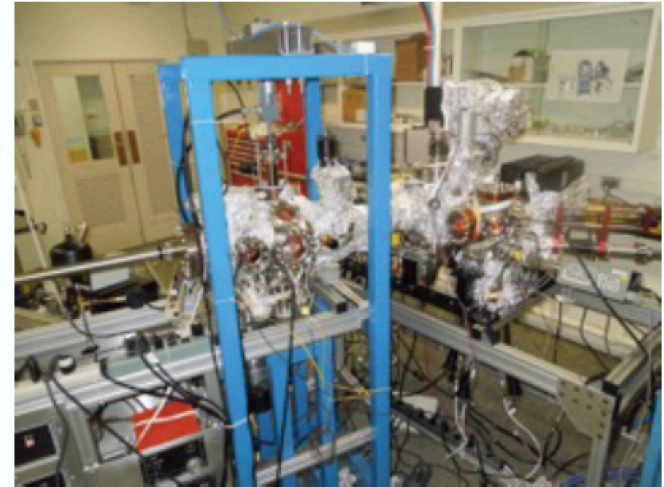
SPEED

Large Area Picosecond Photodetectors (LAPPD's)



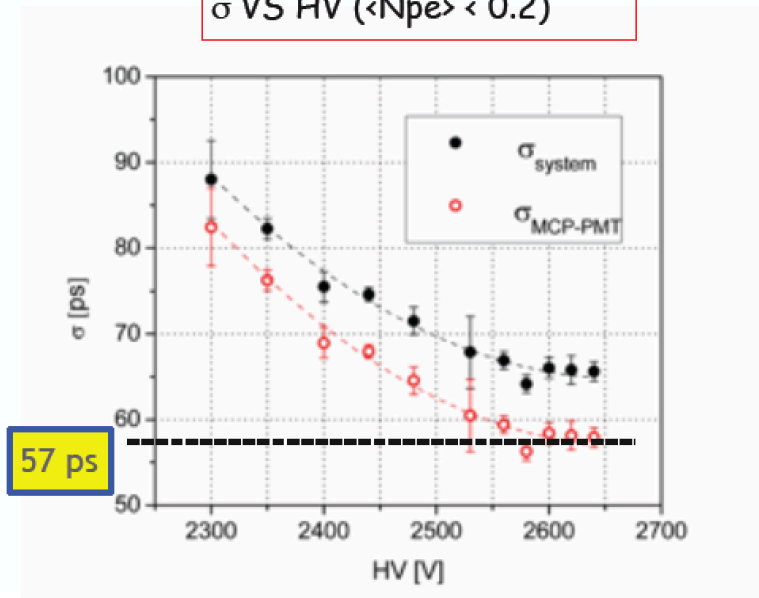
▶ ~1 device / 2 weeks

ANL is producing small quantities of 6 cm MCP's



Argonne Small Tube Processing System

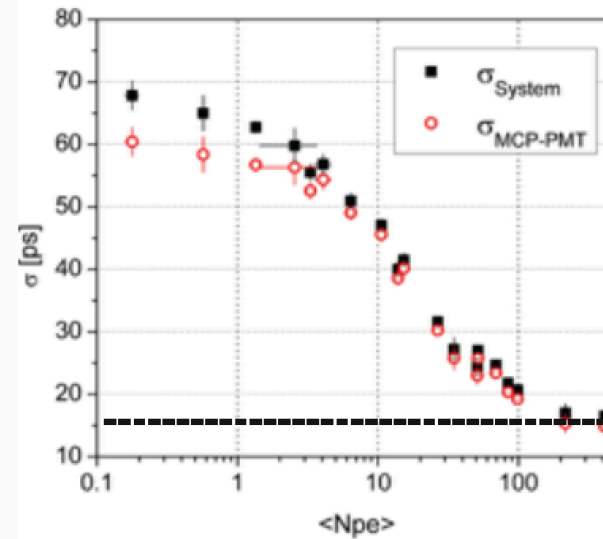
σ VS HV ($\langle N_{pe} \rangle < 0.2$)



57 ps

σ VS $\langle N_{pe} \rangle$

HV=2560V



15 ps

Now investigating behavior in cryogenic environment



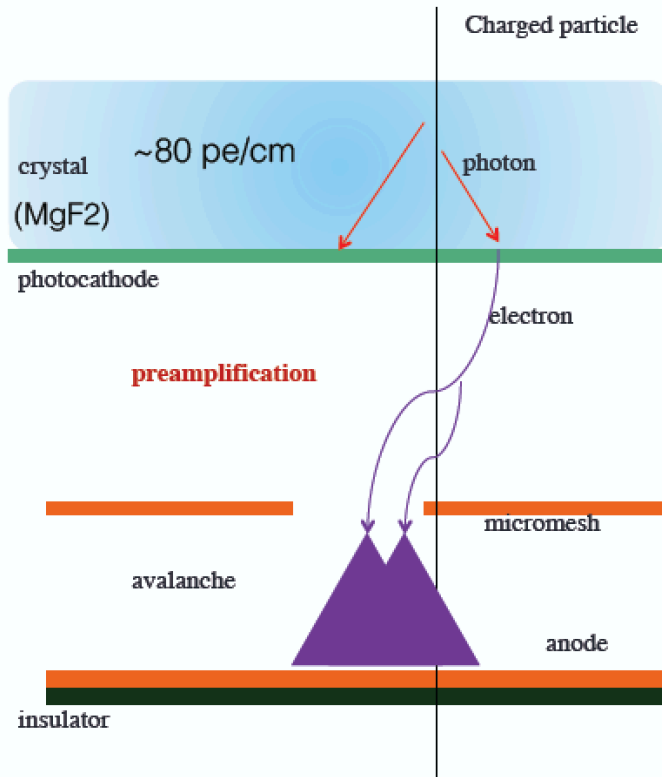
Large Area Photodetectors based on MicroPattern Sensors

Sebastian White CERN/Princeton

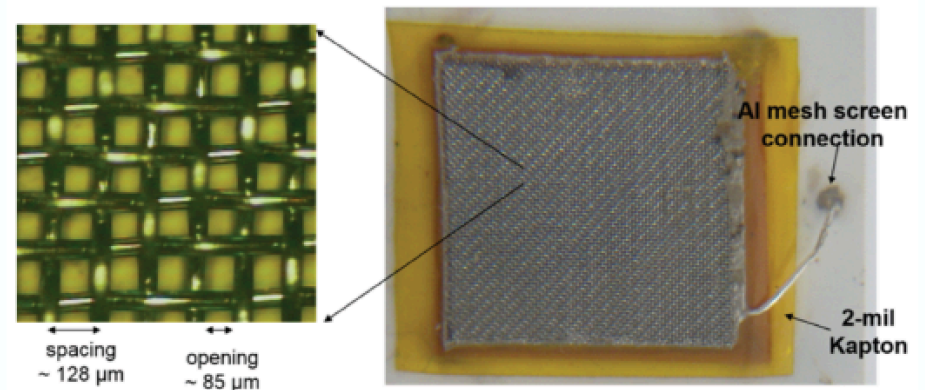
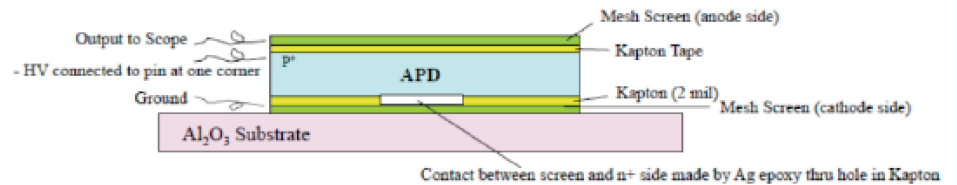
CPAD mtg. UT Arlington Oct 6, 2015

Gas MIP sensor retooled
->photosensor

Si photosensor retooled
->MIP sensor

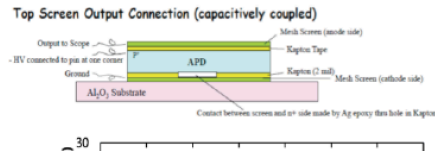
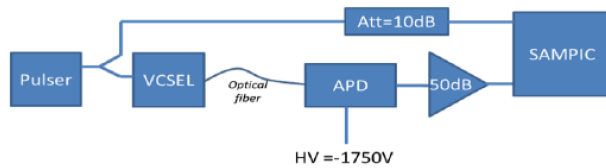
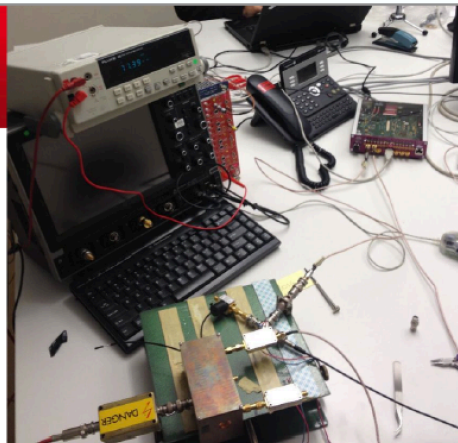


Top Screen Output Connection (capacitively coupled)



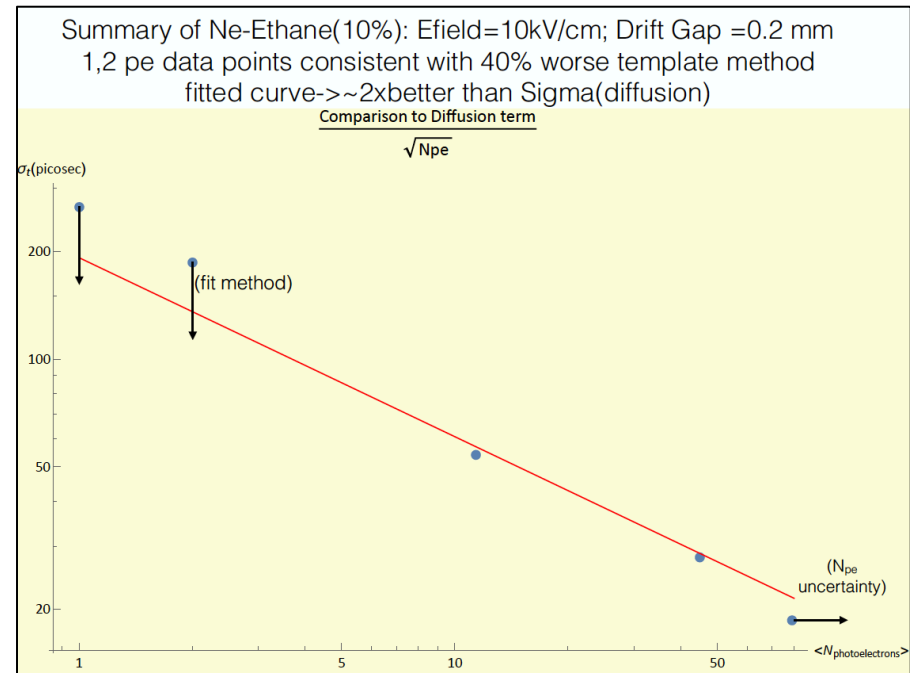
MEASURING PICOSECONDS ...

- SAMPIC module has been connected to **S.White's fast mesh-APD** at CERN (see S.White's poster).
- Goal : measure the **time difference between the pulser and the APD signal** => detector time resolution
- All measurements below performed in **~1 hour**.
- Best measurement **< 10 ps rms**



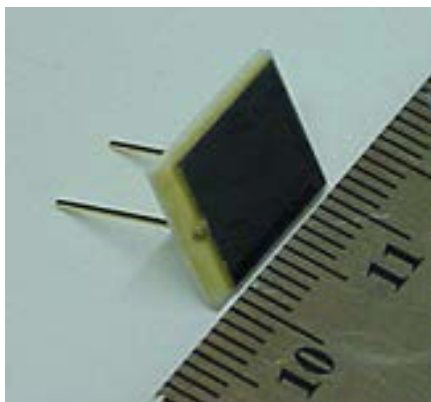
Timing of APD and Micromegas
has been measured in
the lab

Talk has a discussion of low
cost of production

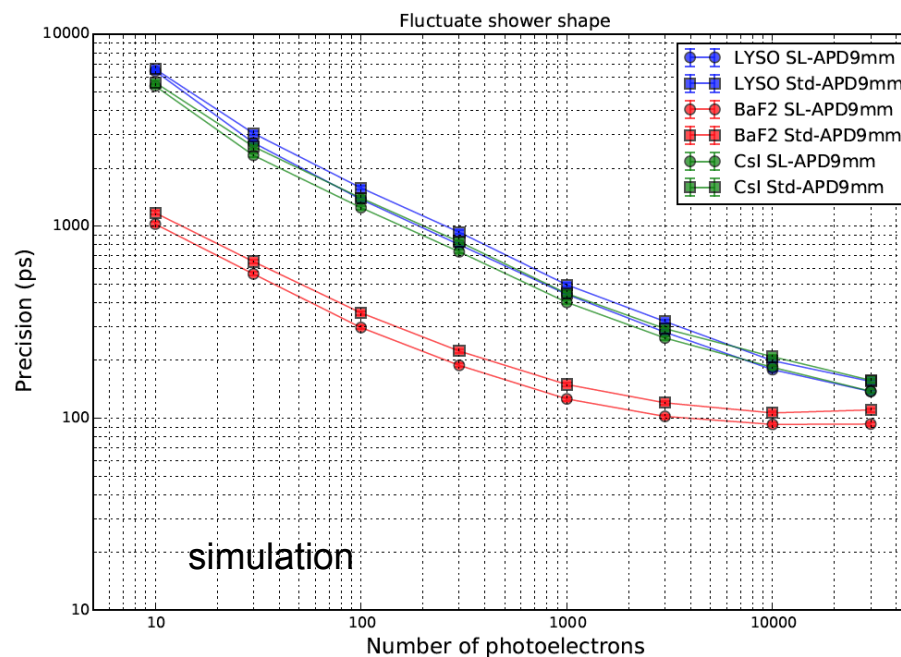
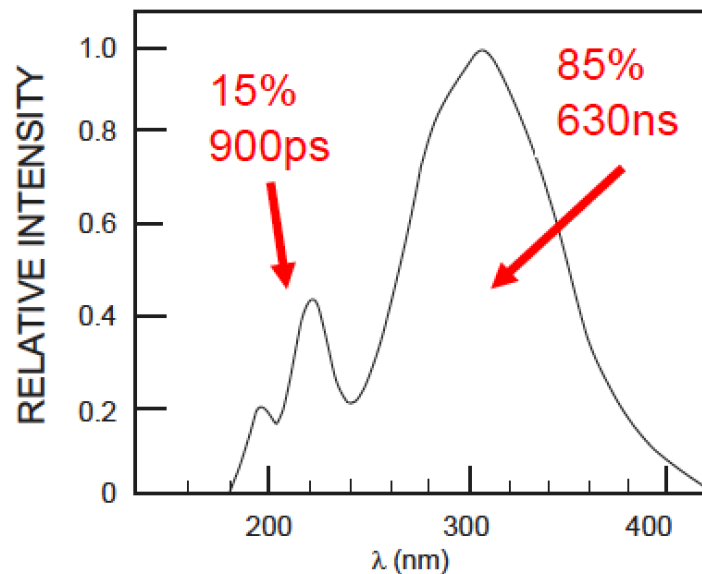


Development of a large area APD for readout of Barium Fluoride crystals

- The baseline uses barium fluoride crystals:
 - Fast decay time → short integration time, high rate capability
 - Good energy and time resolution
 - Radiation hardness
 - Suitability for a possible Mu2e upgrade



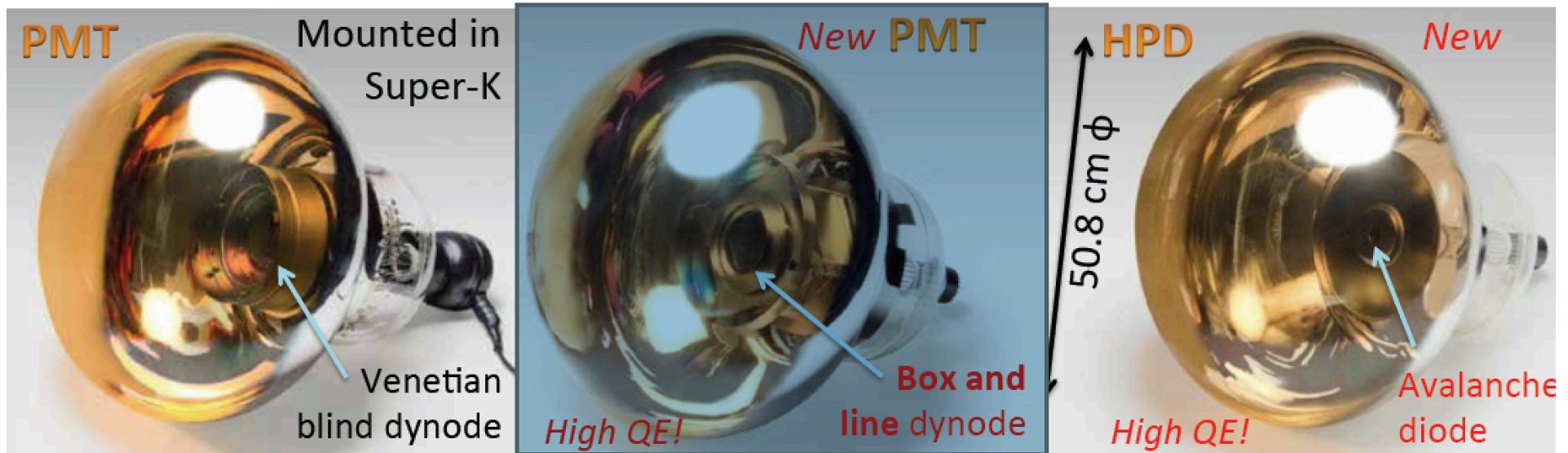
Modification of 9x9mm solar blind APD based on existing RMD device



New Photodetectors

By Hamamatsu Photonics K.K.

- New 50 cm Φ photodetectors developed for HK.

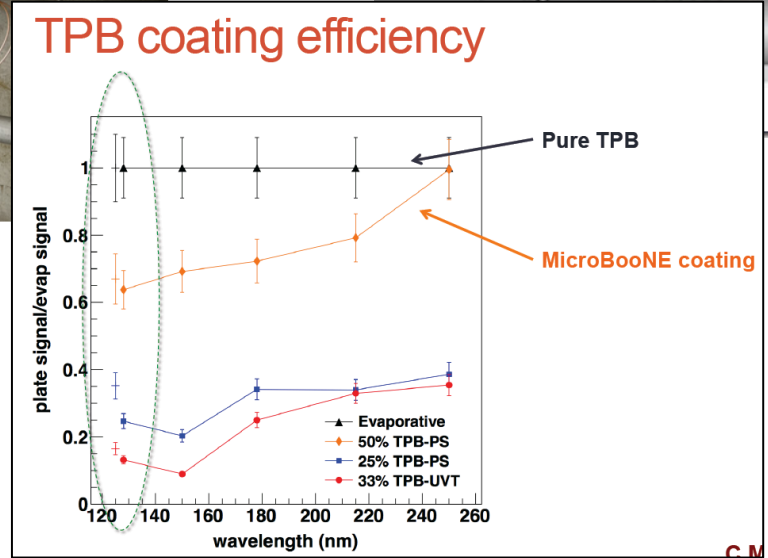
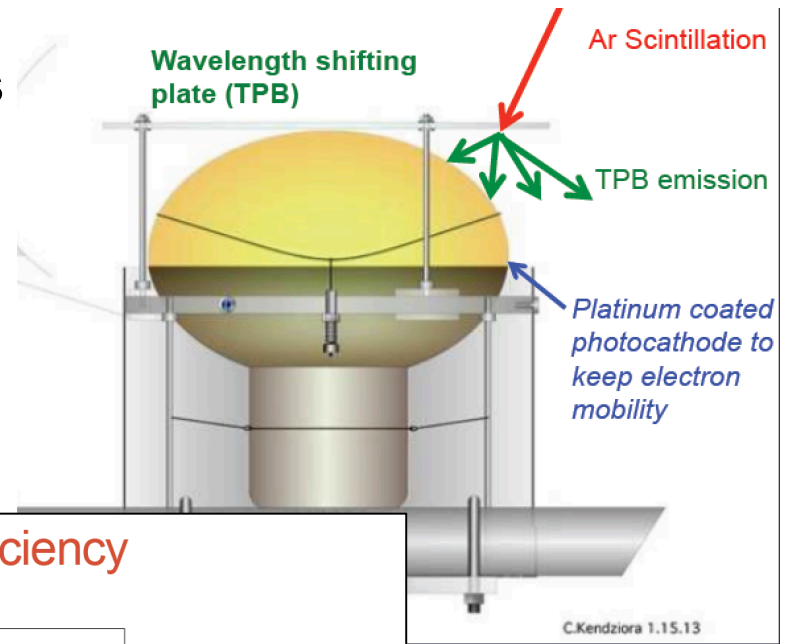


Model	R3600 (Used for 2-30 yrs)	R12860	R12850
Amplification	Venetian blind dynode	Box and line dynode	20mm Φ Avalanche diode
Q.E.	~22%	~30%	~30%
C.E. Φ 46 (Φ 50)	67% (61%)	95% (85%)†	93% (76%) w/ 5ch AD†
T.T.S. (FWHM)	5.5 ns	2.7 ns	0.75ns (w/o Preamp.)
Bias voltage	2 kV bias	2 kV bias	8 kV bias + AD bias (<1kV)
Proof test	1.8 yrs for HQE	0.8 yrs now from Sep.2014	> 0.5 yrs expected

† still in R&D

SPECTRAL SENSITIVITY

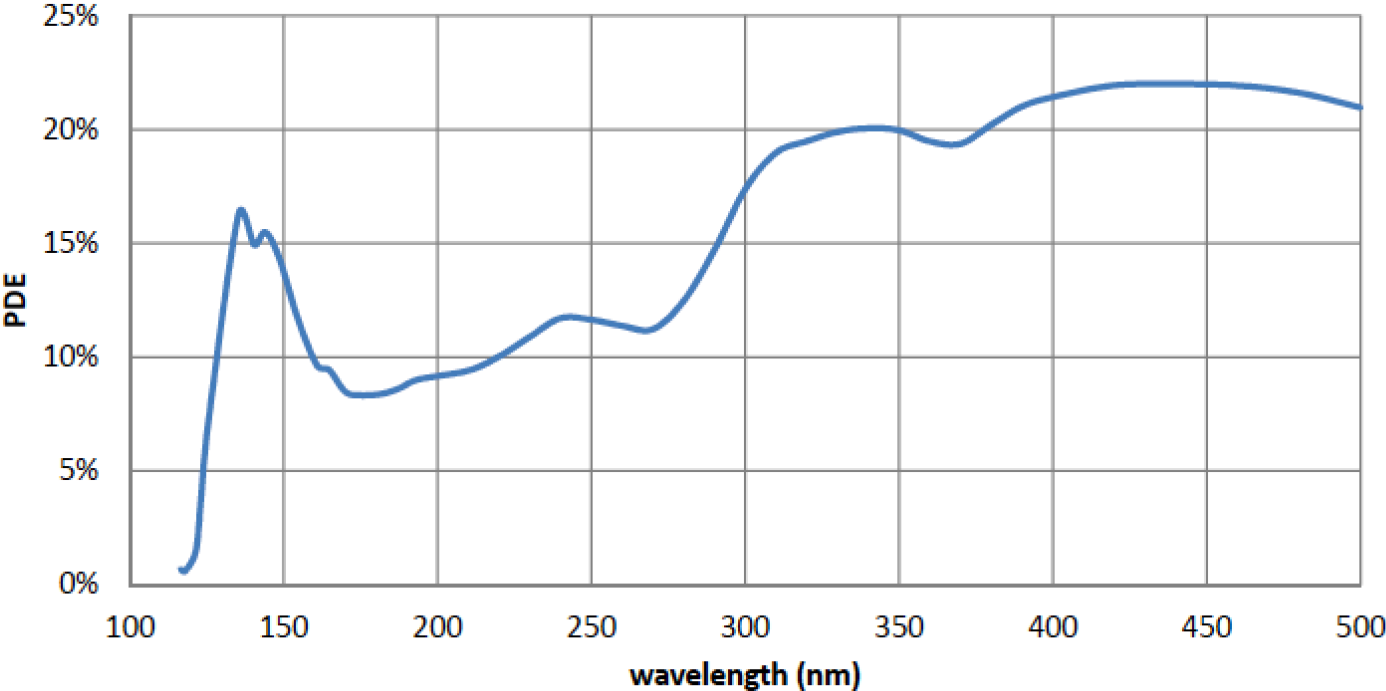
MicroBooNE uses Hamamatsu 5912 PMT's modified for cryogenic environment. Solve spectral response problem with TPB



Hamamatsu work on direct VUV detection

MPPC for direct detection of VUV

PDE of VUV3 MPPC - 3mm chip w/ 50um pixels
Under vacuum <200nm | In Air >200nm | Gain = 1.25×10^6



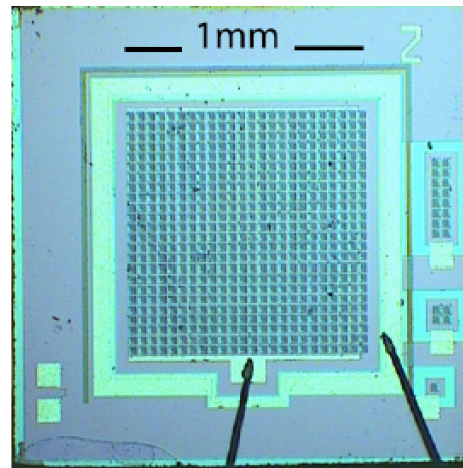
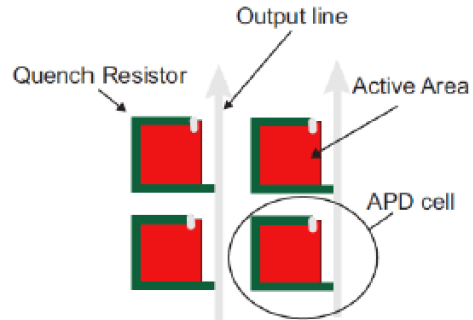
COST

standard PMT costs about \$0.02/mm²

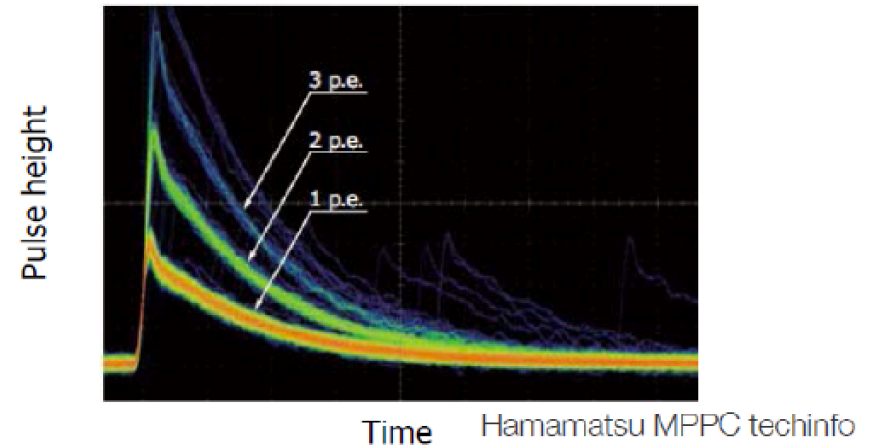
to be **low cost**, that is the goal you must reach

SIZE

The SiPM

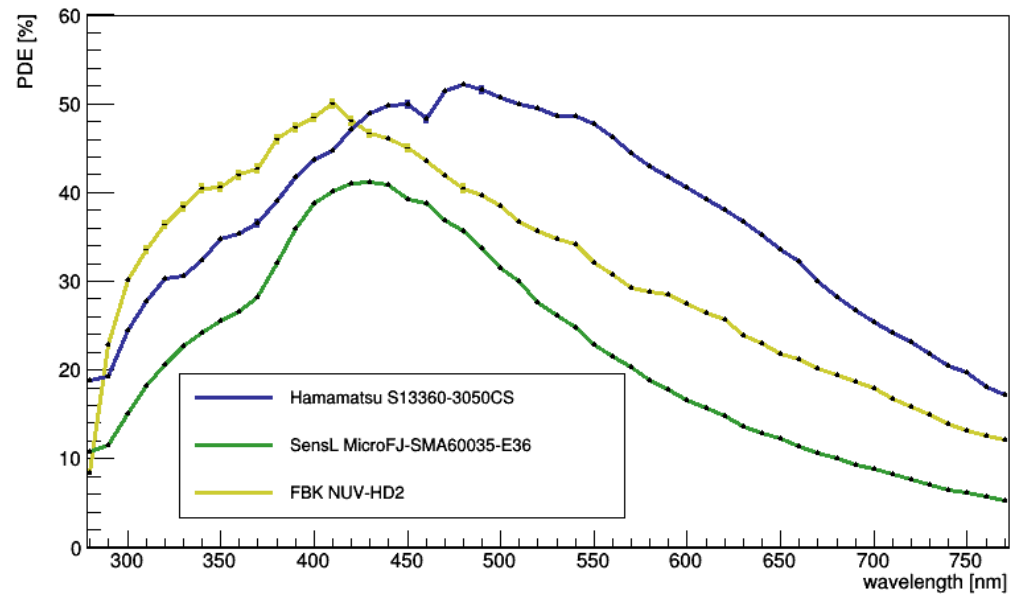
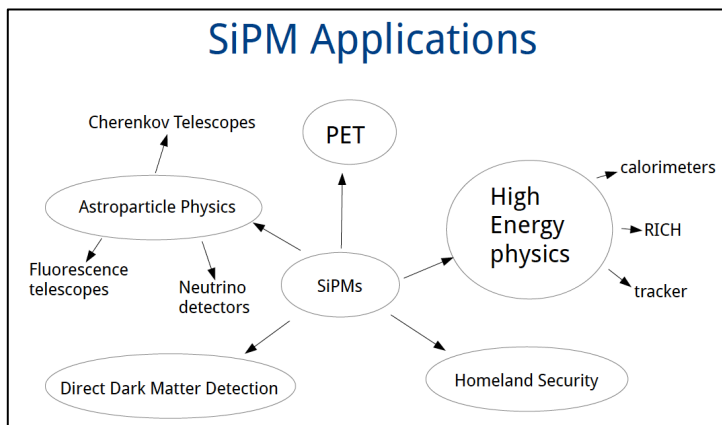
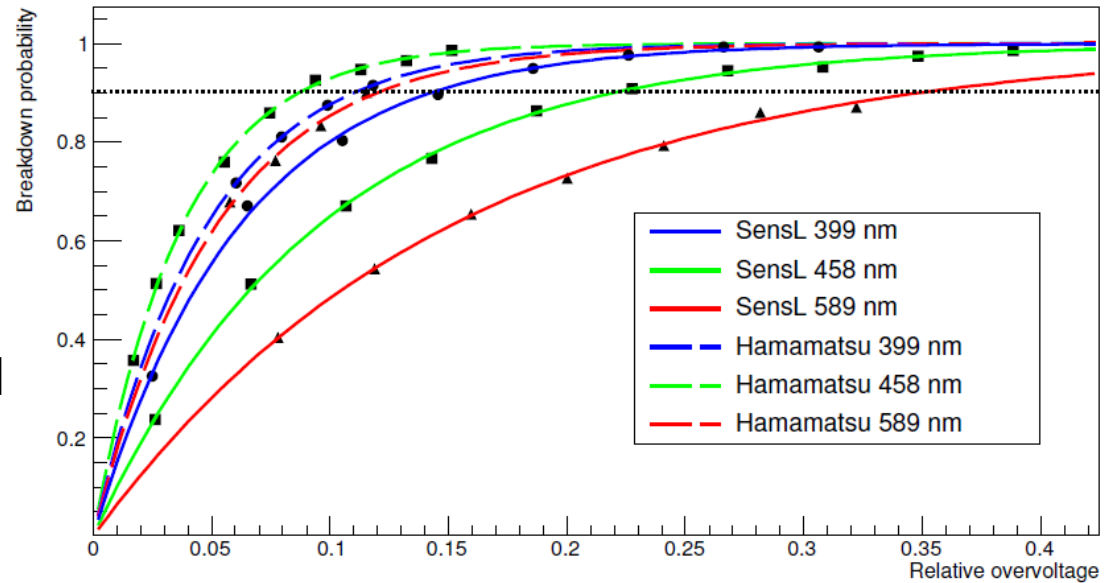


MEPhI/Pulsar SiPM 2004



The SiPM concept provides multi-photon resolution:

Due to widespread application the commercial development has proceeded rapidly in terms of efficiency and cost



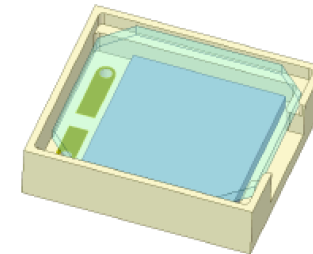
RADIOPURITY

MPPC Packaging: Ultralow RI materials

For direct detection of VUV (128 or 175nm)

Window material: synthetic silica (quartz) for 175nm | none for 125nm

Package material candidates: ceramic, synthetic sapphire, quartz + TGV, intrinsic silicon, etc.



Example: ceramic package + quartz window

For detection of wavelength-shifted 420nm signal

Window material: various kinds of resin

Package material candidates: various kinds of resin

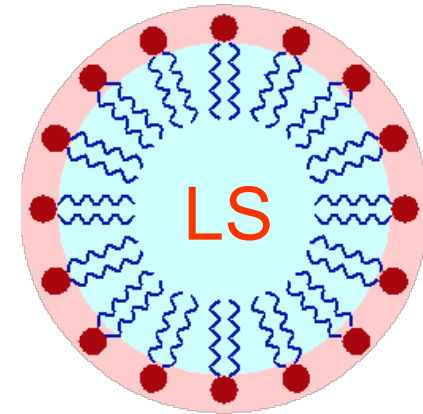


ENERGY TO LIGHT CONVERSION

Water-based Liquid Scintillator

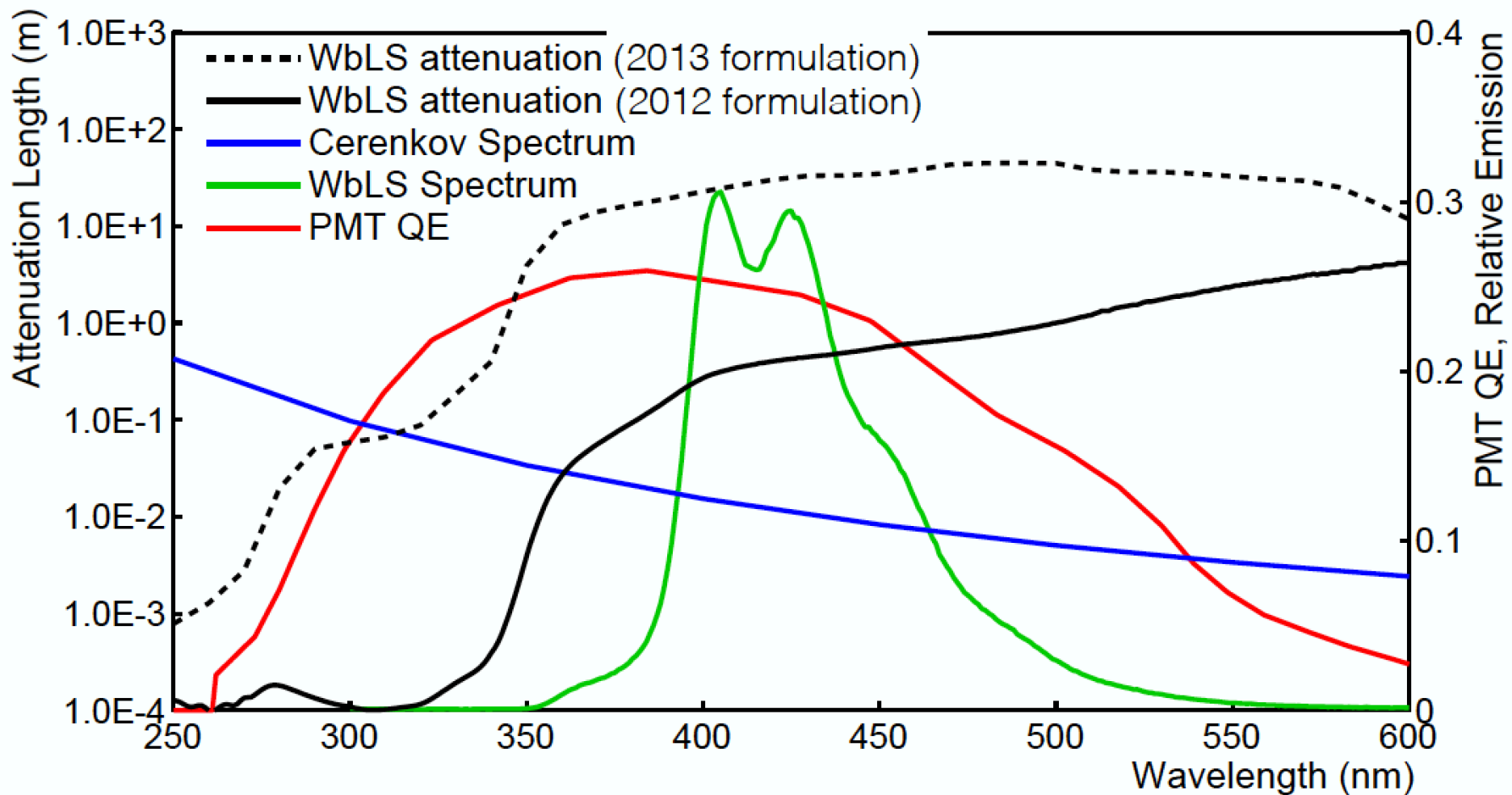


Brookhaven National Lab

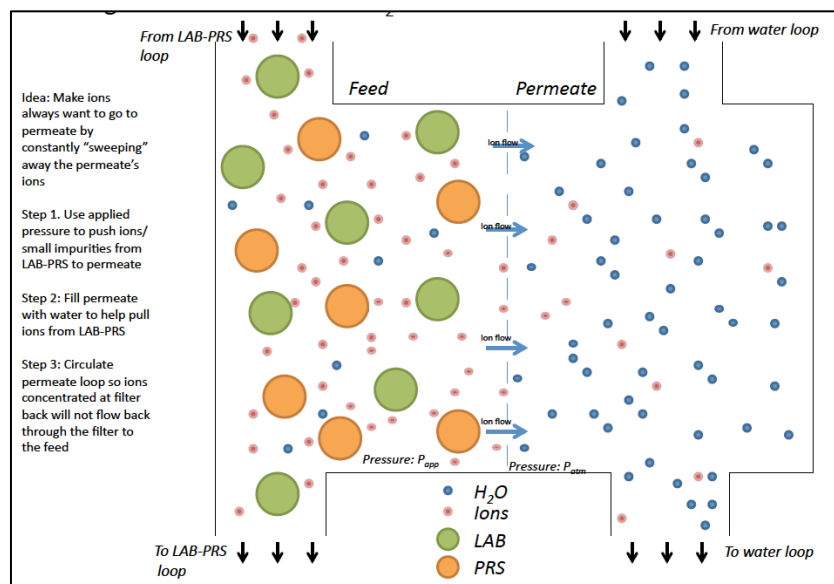


water

Big News is that this now exists in 100 liter quantities



Light yield for these processes is comparable for <10% concentration WbLS. Disentangling them and understanding the details of wavelength-dependence is the main focus of R&D.

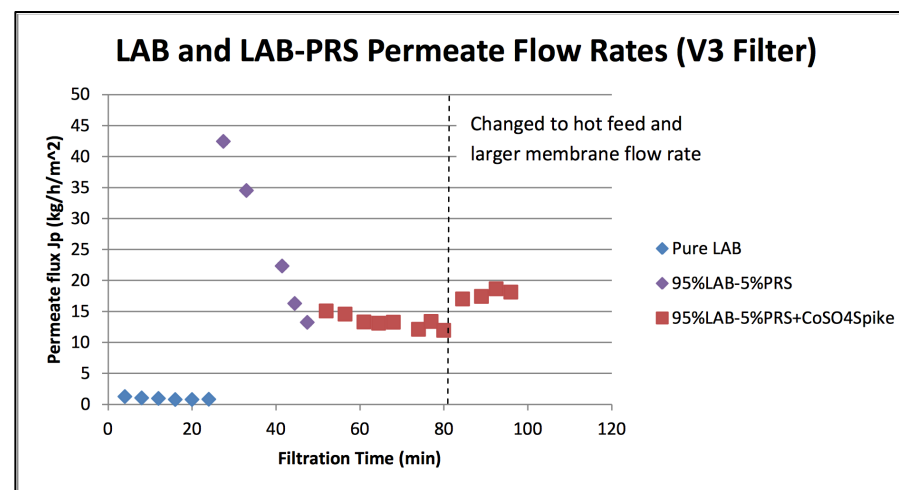


Related Problem: how to purify LS and WbLS in-situ?

R&D on use of NanoFiltration (NF)
on organic LS and WbLS

Issues:

Surface charge effects
Concentration Gradients
Flow rates



surfactant compatible materials have
been identified that give adequate flow

Findings

- The development of new photosensors and scintillators has far-reaching application in virtually every area of High Energy Physics
- Speed, Spectral Response, Radiation Hardness, Cryogenic Adaptation, Size, and Cost all important.
- My opinion: any individual device does NOT have to solve all possible problems. **Specialization** for a specific use seems more productive. E.g. SiPM's are not low cost compared to PMT's and perhaps never will be. It is performance that is the selling point if cost is not a major part of the cost of the experiment.

Recommendations/Comments

- Broad applicability of photosensors both in high energy physics and in industry makes it a natural area for SBIR and other partnership-based efforts
- If you develop a good photosensor, there is almost certainly bound to be a good use in HEP
- Expect development to be *difficult!*
- Allow for R&D proposals to compete! (e.g. recent INP FOA discourages rather than encourages R&D – a bad precedent). Not supporting R&D is mortgaging the future. E.g. do we need N+1 LAr prototypes, or a large, fast photosensor?